

ABSTRACT OF THE DISCLOSURE

652329 2024-03-20

An electrophotographic photosensitive member, irradiated with semiconductor laser light having a wavelength of 380 to 500 nm, includes a conductive substrate, a charge-generating layer formed thereon; and a charge transport layer formed thereon, the charge transport layer having a transmittance of at least 30% for the semiconductor laser light. A process cartridge mountable to and detachable from an electrophotographic apparatus includes the electrophotographic photosensitive member. An electrophotographic apparatus also includes the electrophotographic photosensitive member.